

### PNP -3.0A -50V Middle Power Transistor

| Parameter        | Value |
|------------------|-------|
| V <sub>CEO</sub> | -50V  |
| I <sub>C</sub>   | -3.0A |

## ● Features

1) Suitable for Middle Power Driver

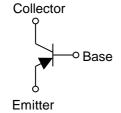
2) Complementary NPN Types: 2SCR533P

3) Low V<sub>CE(sat)</sub>

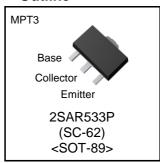
$$V_{CE(sat)} = -0.4V \text{ Max. } (I_C/I_B = -1A/-50\text{mA})$$

4) Lead Free/RoHS Compliant.

### •Inner circuit



## ●Outline



### Applications

Motor driver , LED driver Power supply

## Packaging specifications

| Part No. | Package | Package<br>size<br>(mm) | Taping<br>code | Reel size<br>(mm) | Tape width (mm) | Basic<br>ordering<br>unit (pcs) | Marking |
|----------|---------|-------------------------|----------------|-------------------|-----------------|---------------------------------|---------|
| 2SAR533P | MPT3    | 4540                    | T100           | 180               | 12              | 1,000                           | MM      |

### ● Absolute maximum ratings (Ta = 25°C)

| Parame                       | eter     | Symbol             | Values      | Unit |
|------------------------------|----------|--------------------|-------------|------|
| Collector-base voltage       |          | $V_{CBO}$          | -50         | V    |
| Collector-emitter voltage    |          | V <sub>CEO</sub>   | -50         | V    |
| Emitter-base voltage         |          | $V_{EBO}$          | -6          | V    |
| Collector current            | DC       | I <sub>C</sub>     | -3.0        | Α    |
|                              | Pulsed   | I <sub>CP</sub> *1 | -6.0        | А    |
| Power dissipation            | 2SAR533P | P <sub>D</sub>     | 0.5 *2      | W    |
|                              | ZOAROOOF | ' D                | 2.0 *3      | W    |
| Junction temperature         |          | $T_{j}$            | 150         | °C   |
| Range of storage temperature |          | T <sub>stg</sub>   | −55 to +150 | °C   |

<sup>\*1</sup> Pw=10ms, single pulse \*2 Each terminal mounted on a reference land

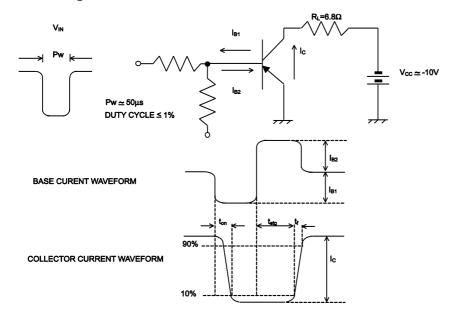
<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7mm)

### ●Electrical characteristics(Ta = 25°C)

| Parameter                            | Symbol                  | Conditions  | Min. | Тур.  | Max.  | Unit |
|--------------------------------------|-------------------------|---|------|-------|-------|------|
| Collector-emitter breakdown voltage  | BV <sub>CEO</sub>       | $I_C = -1mA$  | -50  | -     | -     | V    |
| Collector-base breakdown voltage     | BV <sub>CBO</sub>       | $I_{C} = -100 \mu A$  | -50  | -     | -     | V    |
| Emitter-base breakdown voltage       | BV <sub>EBO</sub>       | $I_E = -100 \mu A$  | -6   | -     | ı     | V    |
| Collector cut-off current            | I <sub>CBO</sub>        | $V_{CB} = -50V$   | ı    | ı     | -1    | μА   |
| Emitter cut-off current              | I <sub>EBO</sub>        | V <sub>EB</sub> = -4V   | -    | -     | -1    | μΑ   |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> *1 | $I_C = -1A, I_B = -50mA$  | -    | -0.20 | -0.40 | V    |
| DC current gain                      | h <sub>FE</sub>         | $V_{CE} = -3V, I_{C} = -50 \text{mA}$                           | 180  | -     | 450   | -    |
| Transition frequency                 | f <sub>⊤</sub>          | $V_{CE} = -10V, I_{E} = -500 \text{mA}$<br>f=100MH <sub>Z</sub> | -    | 300   | -     | MHz  |
| Output capacitance                   | C <sub>ob</sub>         | $V_{CB} = -10V$ , $I_E = 0A$<br>f = 1MHz                        | -    | 24    | -     | pF   |
| Turn-on time                         | t <sub>on</sub> *2      | I <sub>C</sub> = -1.5A  | -    | 45    | ı     | ns   |
| Storage time                         | t <sub>stg</sub> *2     | I <sub>B1</sub> = -150mA<br>I <sub>B2</sub> =150mA              | -    | 250   | ı     | ns   |
| Fall time                            | t <sub>f</sub> *2       | V <sub>cc</sub> ≃ –10V  | -    | 35    | -     | ns   |

<sup>\*1</sup> Pulsed

## •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

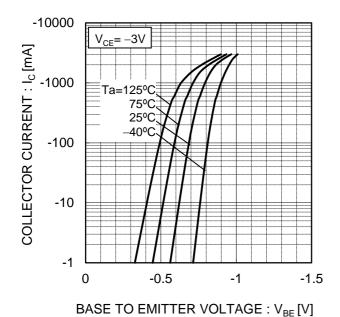
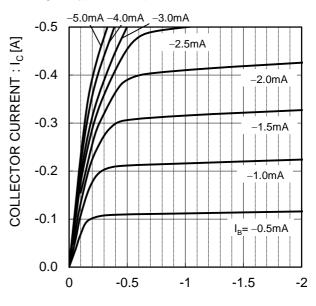


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE: V<sub>CE</sub>[V]

Fig.3 DC Current Gain vs. Collector Current(I)

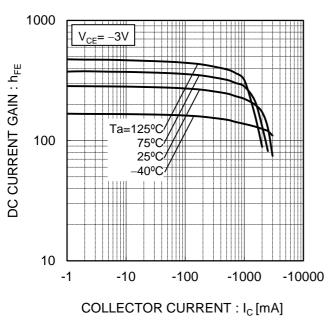
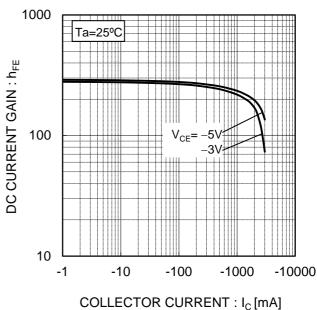
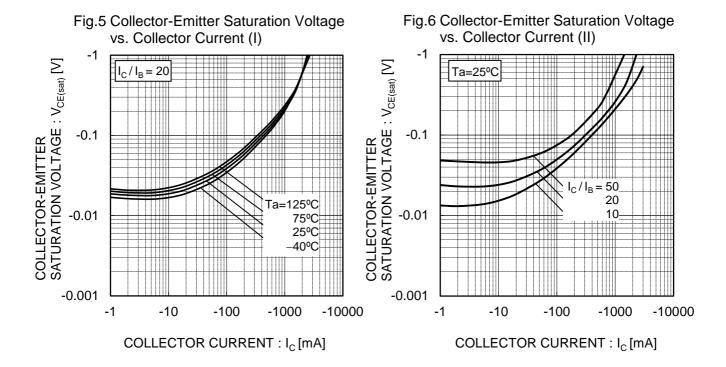
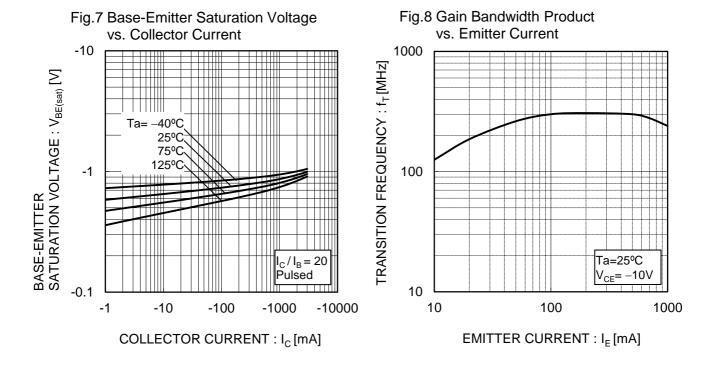


Fig.4 DC current gain vs. output current (II)



### ●Electrical characteristic curves(Ta = 25°C)





### ●Electrical characteristic curves(Ta = 25°C)

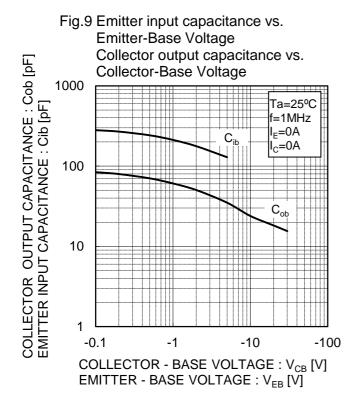
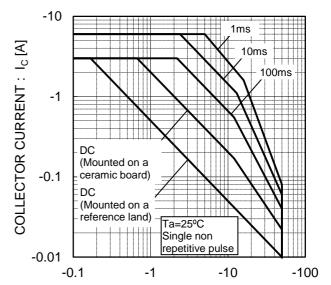
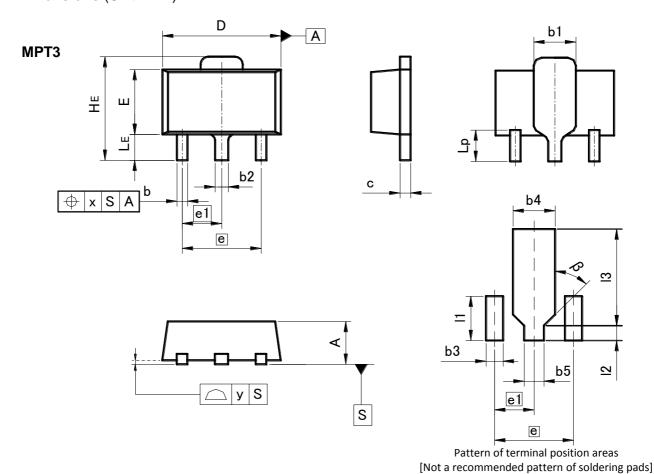


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}[V]$ 

## ●Dimensions (Unit : mm)



| DIM | MILIM | ETERS | INCHES |       |  |
|-----|-------|-------|--------|-------|--|
| DIM | MIN   | MAX   | MIN    | MAX   |  |
| Α   | 1.40  | 1.50  | 0.055  | 0.059 |  |
| b   | 0.30  | 0.50  | 0.012  | 0.020 |  |
| b1  | 1.50  | 1.70  | 0.059  | 0.067 |  |
| b2  | 0.40  | 0.60  | 0.016  | 0.024 |  |
| С   | 0.35  | 0.50  | 0.014  | 0.020 |  |
| D   | 4.40  | 4.70  | 0.173  | 0.185 |  |
| Е   | 2.40  | 2.70  | 0.094  | 0.106 |  |
| е   | 3.0   | 00    | 0.118  |       |  |
| e1  | 1.    | 50    | 0.059  |       |  |
| HE  | 3.70  | 4.30  | 0.146  | 0.169 |  |
| LE  | 0.80  | 1.20  | 0.031  | 0.047 |  |
| Lp  | 1.01  | 1.41  | 0.040  | 0.056 |  |
| Х   | _     | 0.15  | -      | 0.006 |  |
| У   | _     | 0.10  | -      | 0.004 |  |

| DIM | MILIMI | ETERS | INCHES |       |  |
|-----|--------|-------|--------|-------|--|
|     | MIN    | MAX   | MIN    | MAX   |  |
| b3  | _      | 0.65  | -      | 0.026 |  |
| b4  | -      | 1.70  | _      | 0.067 |  |
| b5  | -      | 0.75  | _      | 0.030 |  |
| l1  | -      | 1.71  | 1      | 0.067 |  |
| 12  | -      | 0.58  | 1      | 0.023 |  |
| 13  | _      | 3.72  | -      | 0.146 |  |
| β   | 45°    |       | 45°    |       |  |

Dimension in mm / inches

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